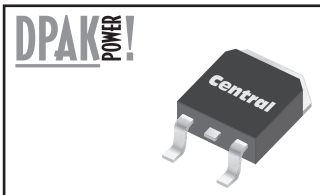
CJD112 NPN
CJD117 PNP

SURFACE MOUNT SILICON COMPLEMENTARY POWER DARLINGTON TRANSISTORS



DPAK CASE

Central Semiconductor Corp.

www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CJD112 and CJD117 are complementary silicon power Darlington transistors manufactured in a surface mount package designed for low speed switching and amplifier applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T_C=25°C unless otherwise noted)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	100	V
Collector-Emitter Voltage	V_{CEO}	100	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Continuous Collector Current	I_C	2.0	A
Peak Collector Current	I_{CM}	4.0	A
Continuous Base Current	I_B	50	mA
Power Dissipation	P_D	20	W
Power Dissipation (T_A=25°C)	P_D	1.75	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	°C
Thermal Resistance	Θ_{JC}	6.25	°C/W
Thermal Resistance	Θ_{JA}	71.4	°C/W

ELECTRICAL CHARACTERISTICS: (T_C=25°C unless otherwise noted)

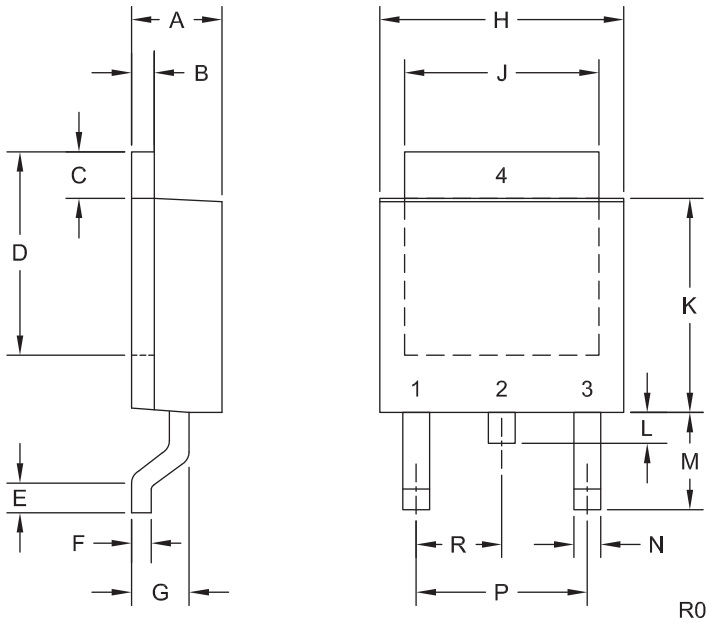
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CEO}	V_{CE}=50V		20	μA
I_{CEV}	V_{CE}=80V, $V_{BE(off)}$=1.5V		10	μA
I_{CEV}	V_{CE}=80V, $V_{BE(off)}$=1.5V, T_C=125°C		500	μA
I_{CBO}	V_{CB}=80V		10	μA
I_{CBO}	V_{CB}=100V		20	μA
I_{EBO}	V_{EB}=5.0V		2.0	mA
BV_{CEO}	I_C=30mA		100	V
$V_{CE(SAT)}$	I_C=2.0A, I_B=8.0mA		2.0	V
$V_{CE(SAT)}$	I_C=4.0A, I_B=40mA		3.0	V
$V_{BE(SAT)}$	I_C=4.0A, I_B=40mA		4.0	V
$V_{BE(ON)}$	V_{CE}=3.0V, I_C=2.0A		2.8	V
h_{FE}	V_{CE}=3.0V, I_C=0.5A	500		
h_{FE}	V_{CE}=3.0V, I_C=2.0A	1000	12000	
h_{FE}	V_{CE}=3.0V, I_C=4.0A	200		
f_T	V_{CE}=10V, I_C=750mA, f=1.0MHz	25		MHz
C_{ob}	V_{CB}=10V, I_E=0, f=0.1MHz (CJD112)		100	pF
C_{ob}	V_{CB}=10V, I_E=0, f=0.1MHz (CJD117)		200	pF

R3 (21-January 2013)

CJD112 NPN
CJD117 PNP

SURFACE MOUNT SILICON
COMPLEMENTARY
POWER DARLINGTON TRANSISTORS

DPAK CASE - MECHANICAL OUTLINE



R0

LEAD CODE:
1) Base
2) Collector
3) Emitter
4) Collector

MARKING:
FULL PART NUMBER

DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
A	0.083	0.108	2.10	2.75
B	0.016	0.032	0.40	0.81
C	0.035	0.063	0.89	1.60
D	0.203	0.228	5.15	5.79
E	0.020	-	0.51	-
F	0.018	0.024	0.45	0.60
G	0.051	0.071	1.30	1.80
H	0.248	0.268	6.30	6.81
J	0.197	0.217	5.00	5.50
K	0.209	0.245	5.30	6.22
L	0.025	0.040	0.64	1.02
M	0.090	0.115	2.30	2.91
N	0.012	0.045	0.30	1.14
P	0.180		4.60	
R	0.090		2.30	

DPAK (REV: R0)

R3 (21-January 2013)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
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- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

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